



Voltage Detectors , ME2807 Series

General Description

ME2807 Series are a set of three-terminal low power voltage detectors implemented in CMOS technology. Each voltage detector in the series detects a particular fixed voltage ranging from 2.0V to 7.0V. The voltage detectors consist of a high precision and low power consumption standard voltage source, a comparator, hysteresis circuit, and an output driver. CMOS technology ensures low power consumption.

Features

- Highly accuracy: $\pm 1\%$
- Low power consumption: TYP 1.8uA ($V_{in}=3V$)
- Detect voltage range : 2.0V~7.0V in 0.1V increments
- Operating voltage range: 1.5V~18V
- Detect voltage temperature characteristics:
TYP $\pm 0.9mV/^{\circ}C$
- Output configuration: CMOS

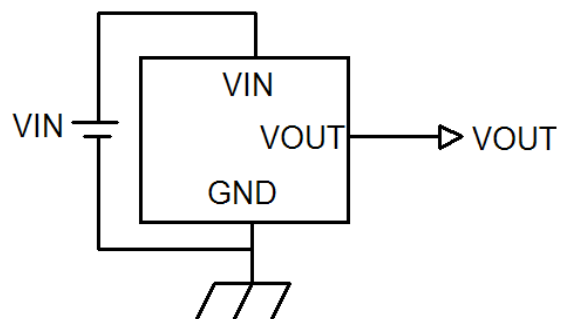
Typical Application

- battery checkers
- Level selectors
- Power failure detectors
- Microcomputer reset
- Battery backup of Memories

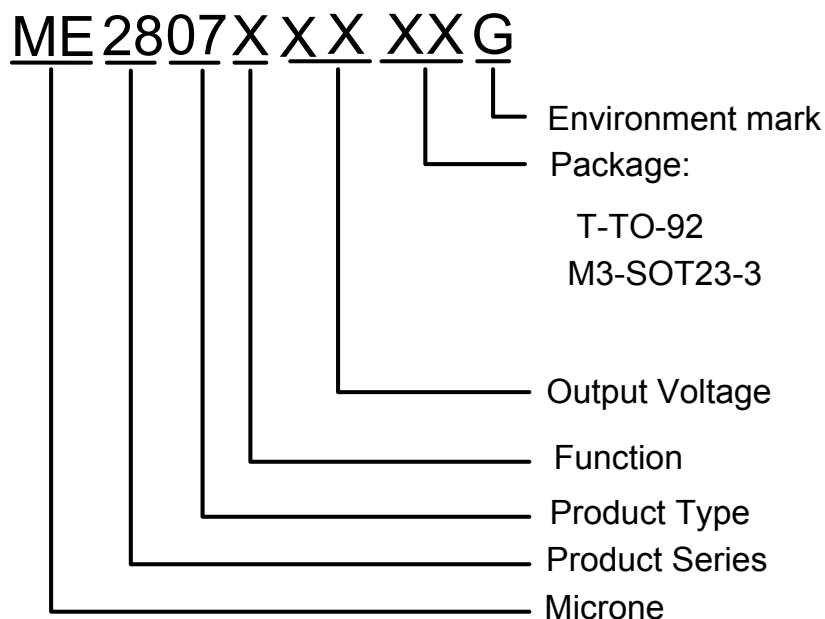
Package

- 3-pin SOT23-3、TO-92

Typical Application Circuit



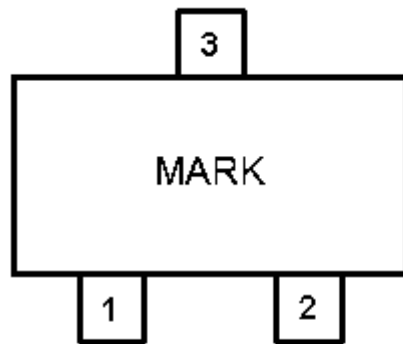
Selection Guide



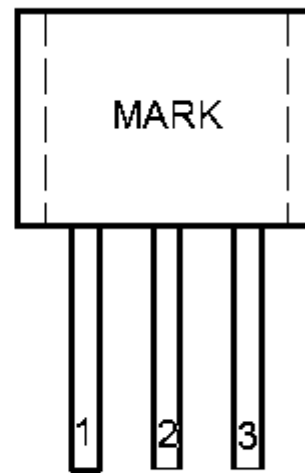
product series	product description
ME2807A22M3G	$V_{OUT} = 2.2V$; Rising edge detection; Package: SOT23-3
ME2807A33M3G	$V_{OUT} = 3.3V$; Rising edge detection; Package: SOT23-3
ME2807A22TG	$V_{OUT} = 2.2V$; Rising edge detection; Package: TO-92
ME2807B33M3G	$V_{OUT} = 3.3V$; Falling edge detection; Package: SOT23-3

NOTE: At present ,there are seventeen kinds of voltage value: 2.2V、2.4V、2.5V、2.7V、2.8V、3.0V、3.2V、3.3V、3.5V、3.6V、3.8V、3.9V、4.0V、4.2V、4.3V、4.5V、5.0V。 If you need other voltage and package, please contact our sales staff.

Pin Configuration



SOT23-3

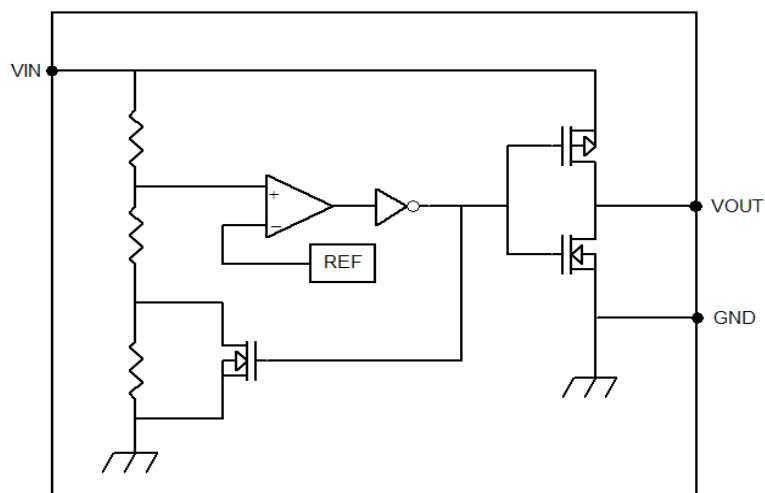


TO-92

Pin Assignment

Pin Number		Pin Name	Functions
SOT-23-3	TO-92		
2	3	GND	Ground
1	1	V _{OUT}	Output Voltage
3	2	V _{IN}	Input Voltage

Block Diagram



Absolute Maximum Ratings

PARAMETER		SYMBAL	RATINGS	UNITS
V_{IN} Input Voltage		V_{IN}	18	V
Output Current		I_{OUT}	50	mA
Output Voltage	CMOS	V_{OUT}	GND-0.3~ $V_{IN} +0.3$	V
Continuous Total Power Dissipation	SOT23-3	P_D	300	mW
	TO-92		500	
Operating Ambient Temperature		T_{Opr}	-40~+85	°C
Storage Temperature		T_{stg}	-50~+125	°C
Soldering temperature and time		T_{solder}	260°C, 10s	

Electrical Characteristics ($V_{DET}=2.0V$ to $7.0V$, $T_A=25^\circ C$, unless otherwise noted)

Parameter	Symbol	Conditions		Min.	Typ.	Max.	Units
V_{DET}	Detect Voltage			$V_{DET} \times 0.99$	V_{DET}	$V_{DET} \times 1.01$	V
V_{HYS}	Hysteresis Width			$V_{DET} \times 0.02$	$V_{DET} \times 0.05$	$V_{DET} \times 0.1$	V
I_{IN}	Operating Current	$V_{DET}=2.0V \sim 2.8V$	$V_{IN}=3.0V$	-	1.8	4	μA
		$V_{DET}=2.8V \sim 3.6V$	$V_{IN}=4.0V$	-	1.8	4	
		$V_{DET}=3.6V \sim 4.7V$	$V_{IN}=5.0V$	-	2.1	7	
		$V_{DET}=4.7V \sim 7.0V$	$V_{IN}=6.0V$	-	2.5	7	
V_{IN}	Operating Voltage	$V_{DET}=2.0V$ to $7.0V$		0.7	-	18	V
I_{OL}	Output Sink Current	$V_{DET}=2.2V$	$V_{IN}=2V$ $V_{OUT}=0.2V$	0.5	1		mA
		$V_{DET}=2.4V$					
		$V_{DET}=2.7V$					
I_{OH}	Output Source Current	$V_{DET}=2.2V$	$V_{IN}=2.5V$ $V_{OUT}=2.2V$	-0.3	-0.5		mA
		$V_{DET}=2.4V$	$V_{IN}=3V$ $V_{OUT}=2.7V$	-0.3	-0.5		
		$V_{DET}=2.7V$	$V_{IN}=3.2V$ $V_{OUT}=2.9V$	-0.3	-0.5		
$\Delta V_{DET}/\Delta T_A$	Temperature characteristics	$0^\circ C \leq T_{opr} \leq 70^\circ C$			± 0.9		mV/°C

Note: 1、VDF(S) : Specified Detection Voltage value
 2、VDF : Actual Detection Voltage value
 3、Release Voltage: $VDR = VDF + V_{HYS}$ (ME2807A series)
 $VDR = VDF - V_{HYS}$ (ME2807B series)

Functional Description

The ME2807 series is a set of voltage detectors equipped with a high stability voltage reference which is connected to the negative input of a comparator — denoted as V_{REF} in the following figure (Fig. 1). When the voltage drop to the positive input of the comparator (i.e., V_B) is higher than V_{REF} , V_{OUT} goes high, M1 turns off, and V_B is expressed as $V_{BH} = V_{IN} \times (R_B + R_C) / (R_A + R_B + R_C)$. If V_{IN} is decreased so that V_B falls to a value that is less than V_{REF} , the comparator output inverts (from high to low), V_{OUT} goes low, V_C is high, M1 turns on, R_C is bypassed, and V_B becomes: $V_{BL} = V_{IN} \times R_B / (R_A + R_B)$, which is less than V_{BH} . By so doing the comparator output will stay low to prevent the circuit from oscillating when $V_B \approx V_{REF}$. If V_{IN} falls below the minimum operating voltage, the output becomes undefined. When V_{IN} goes from low to $V_{IN} \times R_B / (R_A + R_B) > V_{REF}$, the comparator output goes high and V_{OUT} goes high again. The detection voltage is as defined:

$$V_{DET(-)} = (R_A + R_B + R_C) \times V_{REF} / (R_B + R_C)$$

The release voltage is as defined:

$$V_{DET(+)} = (R_A + R_B) \times V_{REF} / R_B$$

The hysteresis width is:

$$V_{HYS} = V_{DET(+)} - V_{DET(-)}$$

Figure 1 demonstrates the CMOS output type with positive output polarity (V_{OUT} is normally high, active low).

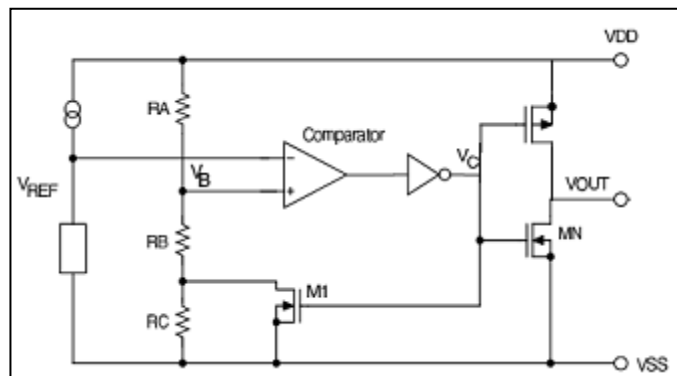
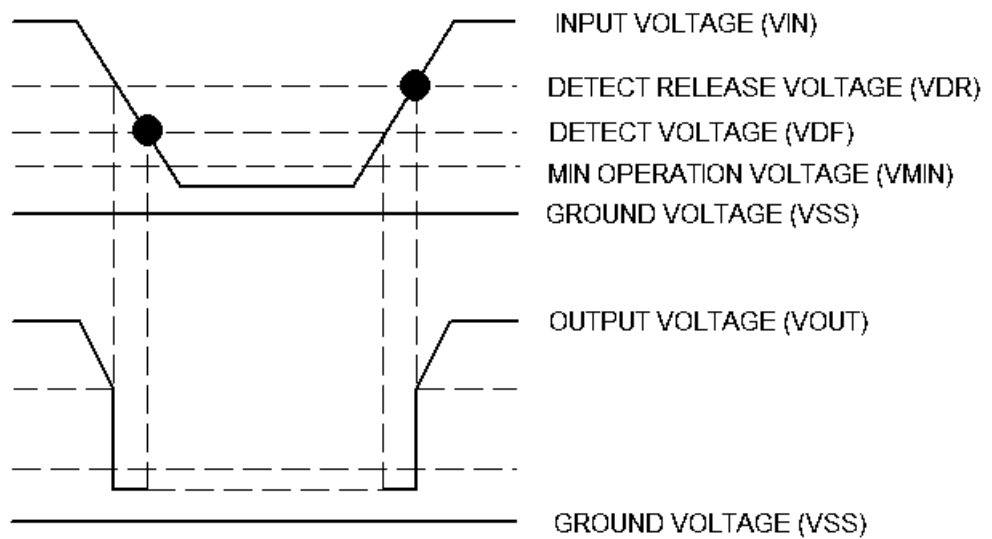


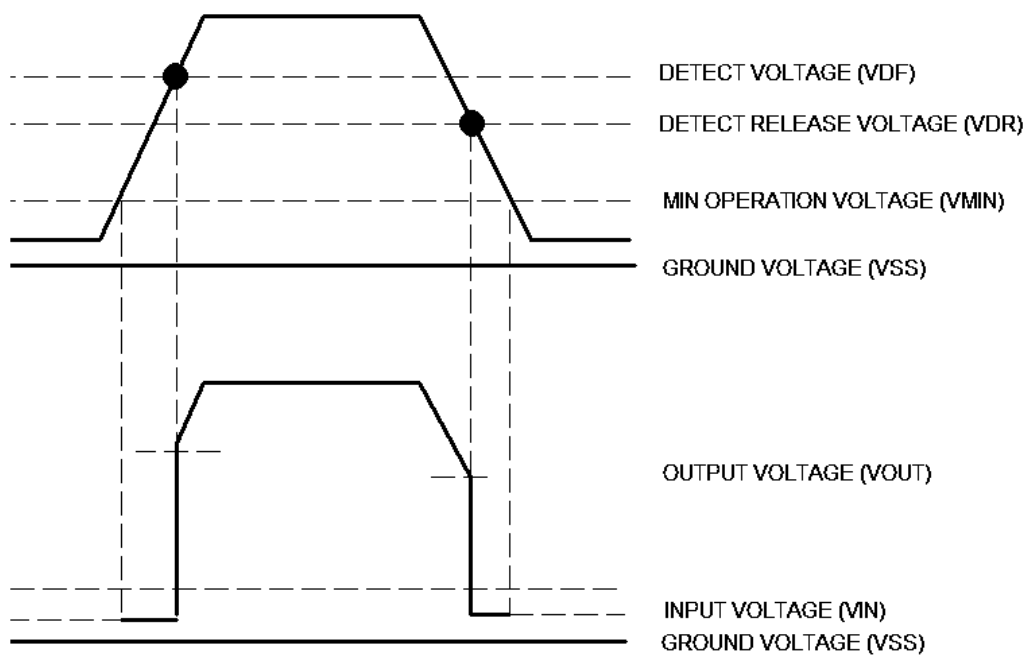
Fig.1 CMOS output voltage detector (ME2807)

Timing Chart

ME2807A:

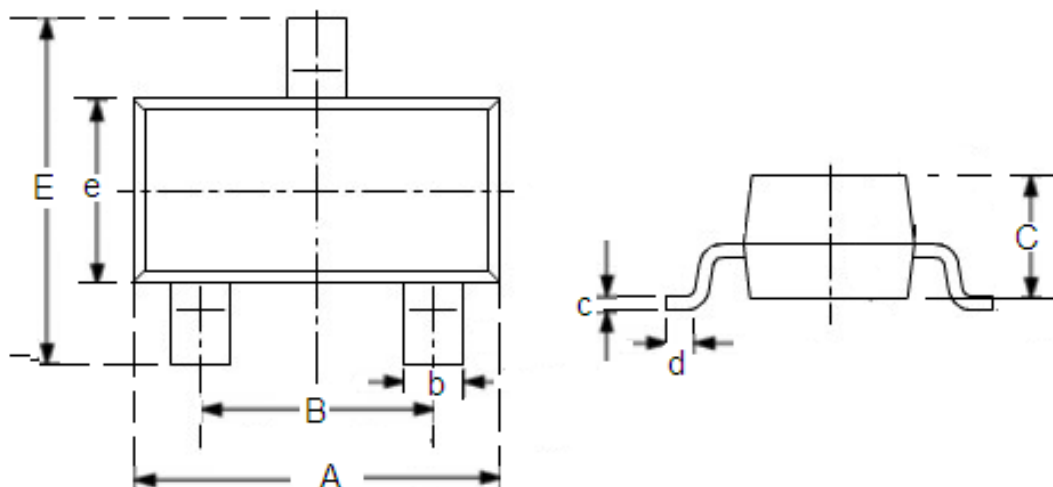


ME2807B:



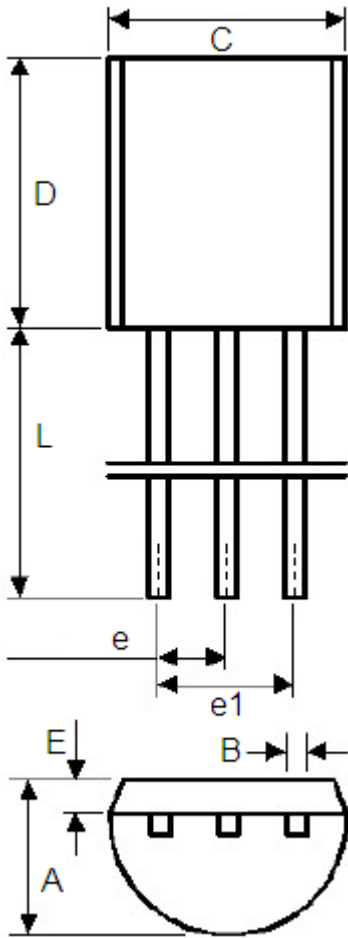
Packaging Information

● SOT23-3



DIM	Millimeters		Inches	
	Min	Max	Min	Max
A	2.7	3.1	0.1063	0.122
B	1.7	2.1	0.0669	0.0827
b	0.35	0.5	0.0138	0.0197
C	1.0	1.2	0.0394	0.0472
c	0.1	0.25	0.0039	0.0098
d	0.2	-	0.0079	-
E	2.6	3.0	0.1023	0.1181
e	1.5	1.8	0.059	0.0708

● TO-92



DIM	Millimeters		Inches	
	Min	Max	Min	Max
A	3.4	3.8	0.13386	0.1496
B	0.3	0.5	0.0118	0.0197
C	4.4	4.8	0.1732	0.189
D	4.4	4.8	0.1732	0.189
E	0.9	1.5	0.0354	0.059
e	1.17	1.37	0.046	0.0539
e1	2.39	2.69	0.094	0.1059
L	12	16	0.4724	0.6299

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